0.9 V to 2.5 V, 55 mΩ Load Switch in WCSP4

DESCRIPTION

SiP32451, SiP32452, and SiP32453 are n-channel integrated high side load switches that operate from 0.9 V to 2.5 V input voltage range.

SiP32451, SiP32452, and SiP32453 have low input logic control threshold that can interface with low voltage control GPIO directly without extra level shift or driver. There is a pull down at this EN logic control pin.

Turn on time is fast, less than 25 µs typically for input voltage of 1.2 V or higher. SiP32451 and SiP32452 have fast turn off delay time of less than 1 µs while SiP32453 features a guaranteed turn off delay of greater than 30 µs, typically 90 µs.

SiP32451 features an output discharge for fast turn off. SiP32451, SiP32452, and SiP32453 are available in compact wafer level CSP package, WCSP4 0.8 mm x 0.8 mm with 0.4 mm pitch.

FEATURES

- Low input voltage, 0.9 V to 2.5 V
- Low R_{ON}, 55 mΩ typical
- Fast turn on time
- Low logic control with hysteresis
- Reverse current blocking when disabled
- Integrated pull down at EN pin
- Output discharge (SiP32451)
- 4 bump WCSP 0.8 mm x 0.8 mm with 0.4 mm pitch package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

HALOGEN FREE Available

APPLICATIONS

- Battery operated devices
- Smart phones
- GPS and PMP
- Computer
- Medical and healthcare equipment
- Industrial and instrument
- Cellular phones and portable media players
- Game console

TYPICAL APPLICATION CIRCUIT

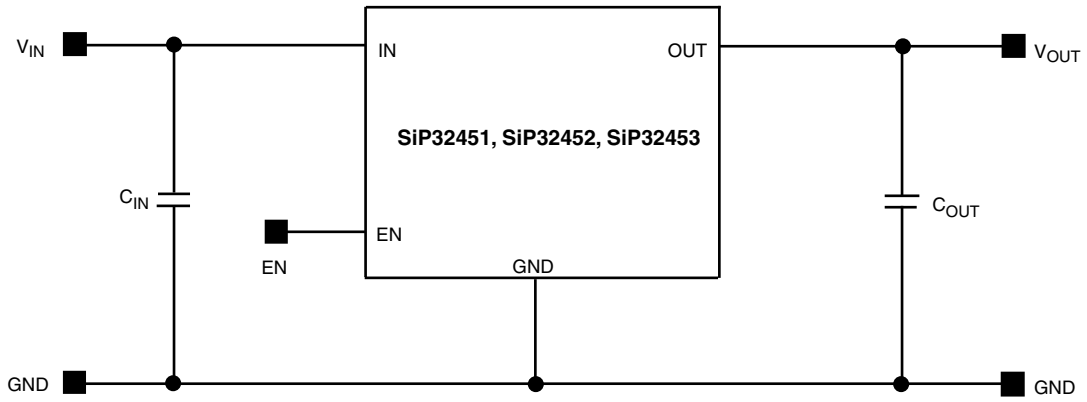

Fig. 1 - SiP32451, SiP32452, and SiP32453 Typical Application Circuit

ORDERING INFORMATION			
TEMPERATURE RANGE	**PACKAGE**	**MARKING**	**PART NUMBER**
-40 °C to +85 °C	WCSP4: 4 bumps (2 x 2, 0.4 mm pitch, 208 µm bump height, 0.8 mm x 0.8 mm die size)	AA	SiP32451DB-T2-GE1
		AB	SiP32452DB-T2-GE1
		AC	SiP32453DB-T2-GE1

Note

- GE1 denotes halogen-free and RoHS-compliant

ABSOLUTE MAXIMUM RATINGS

PARAMETER	LIMIT	UNIT
Supply input voltage (V_{IN})	-0.3 to +2.75	V
Enable input voltage (V_{EN})	-0.3 to +2.75	
Output voltage (V_{OUT})	-0.3 to +2.75	
Maximum continuous switch current ($I_{max.}$)	1.2	A
Maximum pulsed current (I_{DM}) V_{IN} (pulsed at 1 ms, 10 % duty cycle)	2	
ESD rating (HBM)	4000	V
Junction temperature (T_J)	-40 to +150	°C
Thermal resistance (θ_{JA}) [a]	280	°C/W
Power dissipation (P_D) [a]	196	mW

Notes

a. Device mounted with all leads and power pad soldered or welded to PC board

b. Derate 3.6 mW/°C above T_A = 70 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE

PARAMETER	LIMIT	UNIT
Input voltage range (V_{IN})	0.9 to 2.5	V
Operating junction temperature range	-40 to +125	°C

SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED V_{IN} = 1 V, T_A = -40 °C to +85 °C (typical values are at T_A = 25 °C)		LIMITS MIN. [a]	LIMITS TYP. [b]	LIMITS MAX. [a]	UNIT
Operating voltage [c]	V_{IN}			0.9	-	2.5	V
Quiescent current	I_Q	V_{IN} = 1.2 V, V_{EN} = V_{IN}, OUT = open		-	10	15	µA
		V_{IN} = 2.5 V, V_{EN} = V_{IN}, OUT = open		-	34	60	
Off supply current	$I_{Q(off)}$	SiP32451	EN = GND, OUT = open	-	-	30	
		SiP32452, SiP32453		-	-	1	
Off switch current	$I_{DS(off)}$	EN = GND, OUT = 0 V		-	-	30	
Reverse blocking current	I_{RB}	V_{OUT} = 2.5 V, V_{IN} = 0.9 V, V_{EN} = 0 V		-	0.001	10	
On-resistance	$R_{DS(on)}$	V_{IN} = 1 V, I_L = 200 mA, T_A = 25 °C		-	56	65	mΩ
		V_{IN} = 1.2 V, I_L = 200 mA, T_A = 25 °C		-	55	65	
		V_{IN} = 1.8 V, I_L = 200 mA, T_A = 25 °C		-	54	65	
		V_{IN} = 2.5 V, I_L = 200 mA, T_A = 25 °C		-	54	65	
On-resistance temp. coefficient	TC_{RDS}			-	3900	-	ppm/°C
Output pull-down resistance	R_{PD}	V_{EN} = 0 V, T_A = 25 °C (SiP32451 only)		-	425	550	Ω
EN input low voltage [c]	V_{IL}	V_{IN} = 1 V		-	-	0.1	V
EN input high voltage [c]	V_{IH}	V_{IN} = 2.5 V		1.5	-	-	
EN input leakage	I_{EN}	V_{IN} = 2.5 V, V_{EN} = 0 V		-	-	1	µA
		V_{IN} = 2.5 V, V_{EN} = 2.5 V		-	10	15	

SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED V_{IN} = 1 V, T_A = -40 °C to +85 °C (typical values are at T_A = 25 °C)		LIMITS MIN. [a]	LIMITS TYP. [b]	LIMITS MAX. [a]	UNIT
Output turn-on delay time	$t_{d(on)}$	V_{IN} = 1.2 V	R_{LOAD} = 10 Ω, C_L = 0.1 µF, T_A = 25 °C	-	0.4	1	µs
		V_{IN} = 2.5 V		-	0.05	1	
Output turn-on rise time	t_r	V_{IN} = 1.2 V		10	20	30	
		V_{IN} = 2.5 V		5	9.8	20	
Output turn-off delay time	$t_{d(off)}$	SiP32451, SiP32452 V_{IN} = 1.2 V		-	0.25	1	
		SiP32451, SiP32452 V_{IN} = 2.5 V		-	0.15	1	
		SiP32453, V_{IN} = 1.2 V		30	98	150	
		SiP32453, V_{IN} = 2.5 V		30	86	150	

Notes

a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
c. For V_{IN} outside this range consult typical EN threshold curve

PIN CONFIGURATION

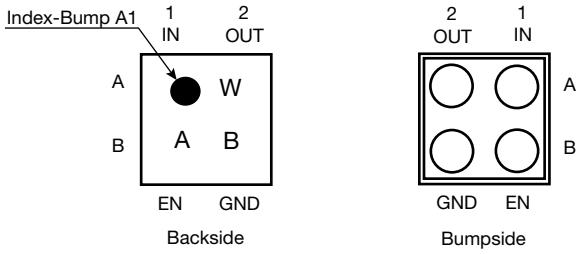

Fig. 2 - WCSP4 2 x 2 Package

PIN DESCRIPTION		
PIN NUMBER	NAME	FUNCTION
A1	IN	This pin is the n-channel MOSFET drain connection. Bypass to ground through a 4.7 µF capacitor
A2	OUT	This pin is the n-channel MOSFET source connection. Bypass to ground through a 0.1 µF capacitor
B1	EN	Enable input
B2	GND	Ground connection

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

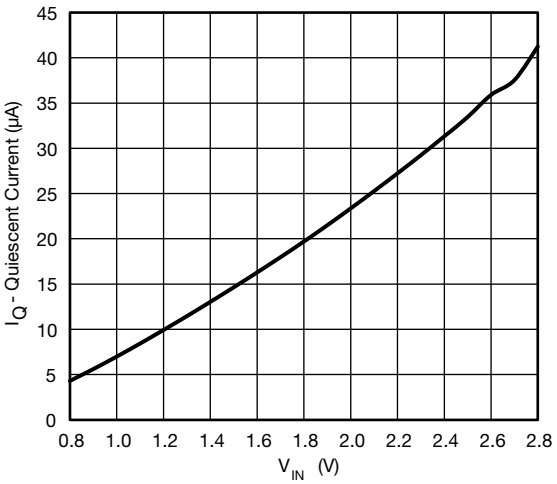

Fig. 3 - Quiescent Current vs. Input Voltage

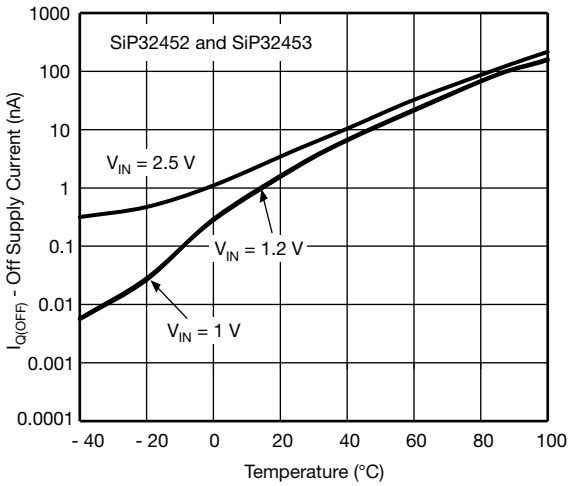

Fig. 6 - Off Supply Current vs. Temperature

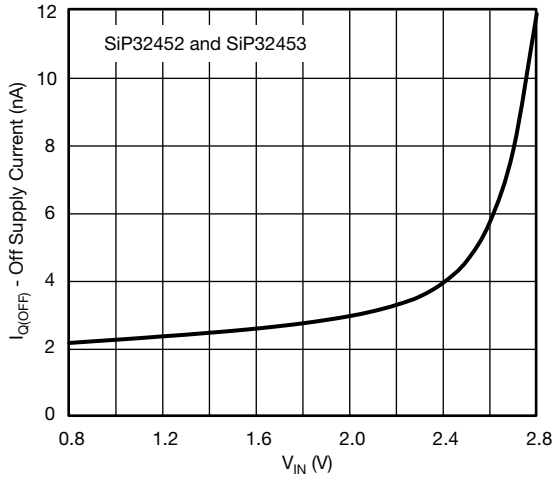

Fig. 4 - Off Supply Current vs. Input Voltage

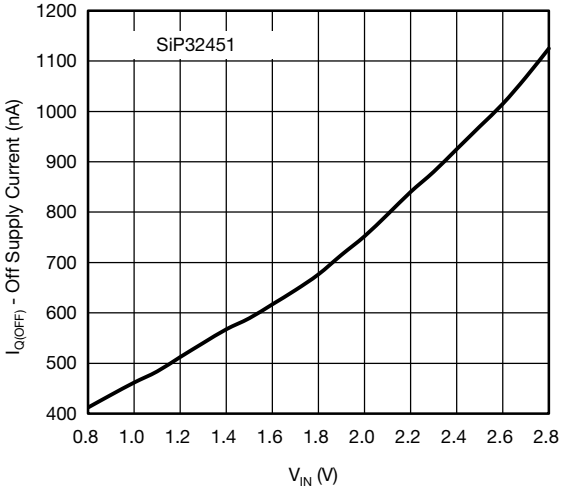

Fig. 7 - Off Supply Current vs. Input Voltage

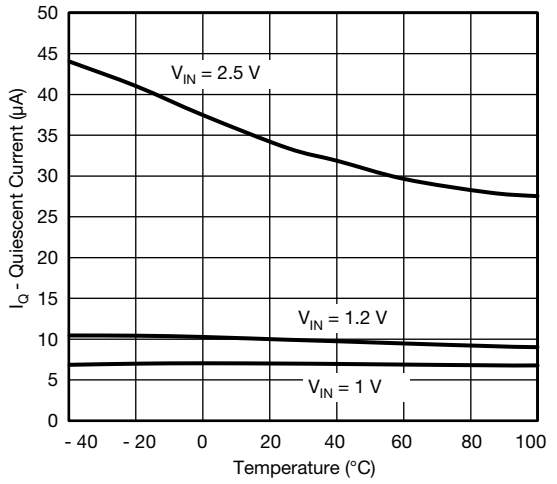

Fig. 5 - Quiescent Current vs. Temperature

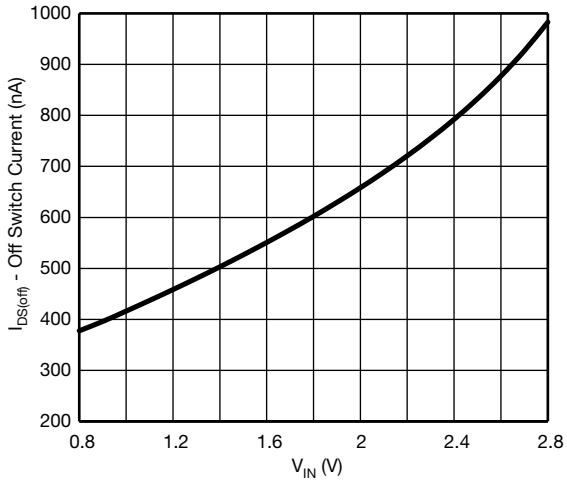

Fig. 8 - Off Switch Current vs. Input Voltage

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

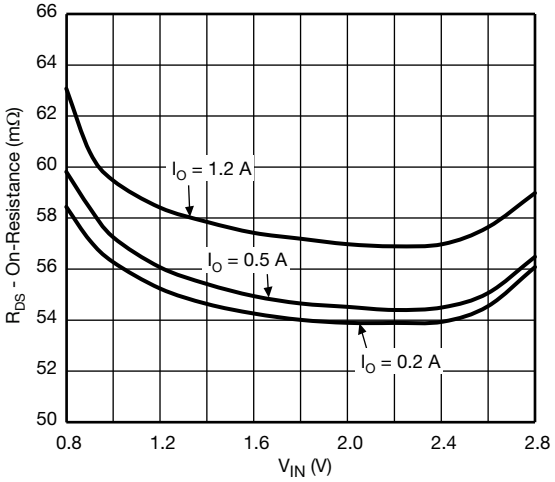

Fig. 9 - $R_{DS(on)}$ vs. V_{IN}

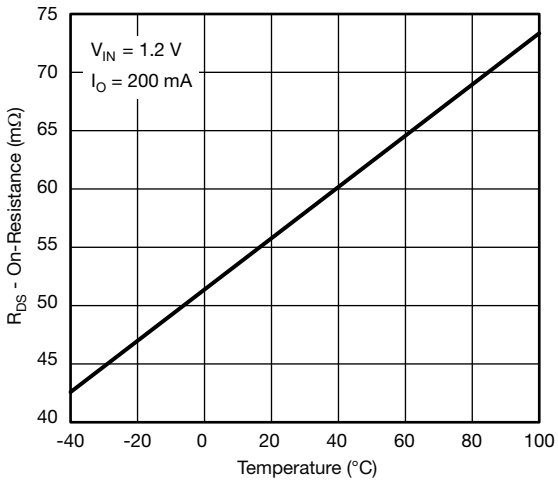

Fig. 12 - $R_{DS(on)}$ vs. Temperature

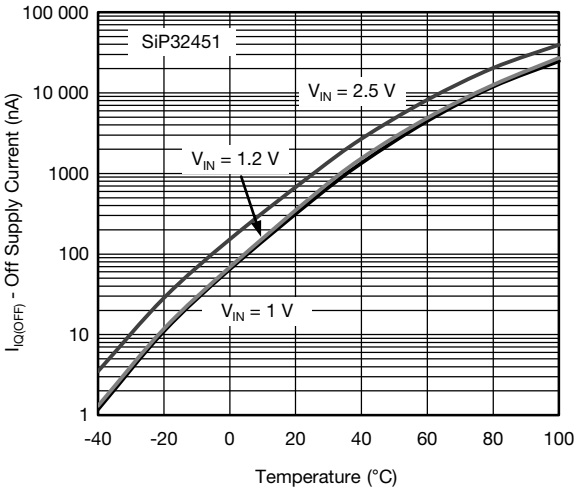

Fig. 10 - Off Supply Current vs. Temperature

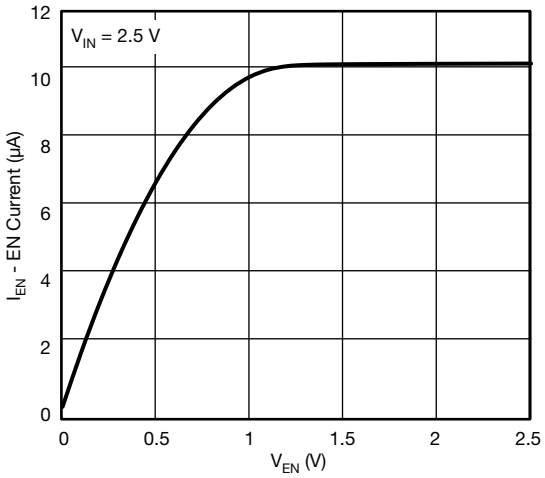

Fig. 13 - I_{EN} vs. V_{EN}

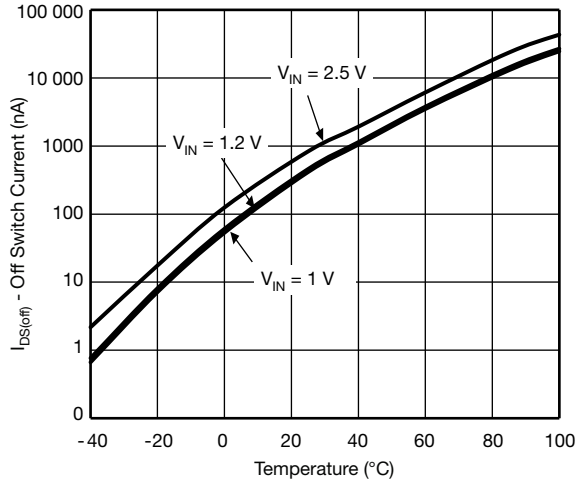

Fig. 11 - Off Switch Current vs. Temperature

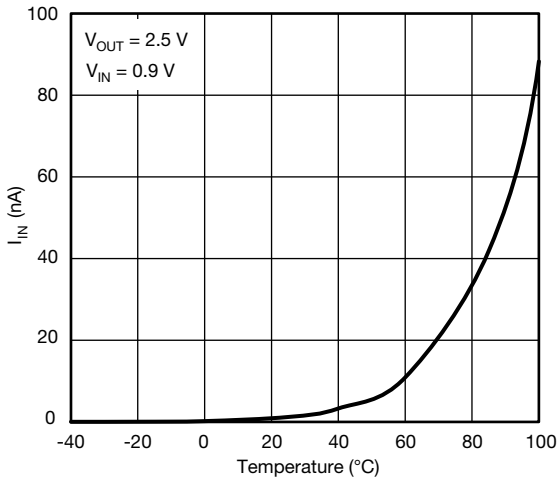

Fig. 14 - Reverse Blocking Current vs. Temperature

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

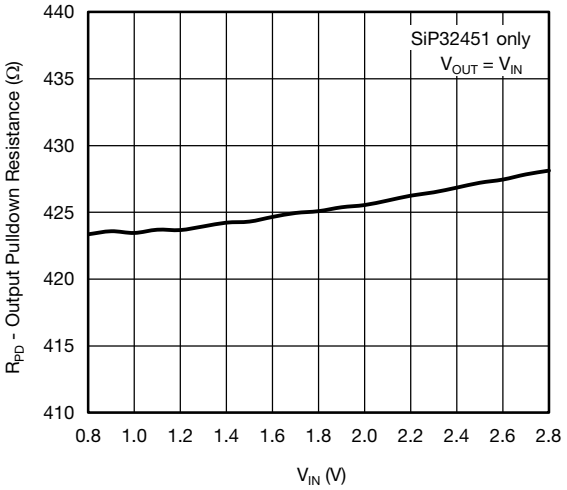

Fig. 15 - Output Pull-down Resistance vs. Input Voltage

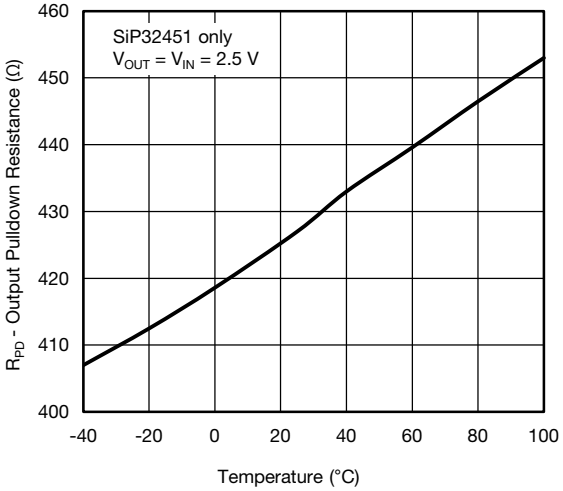

Fig. 18 - Output Pull-down Resistance vs. Temperature

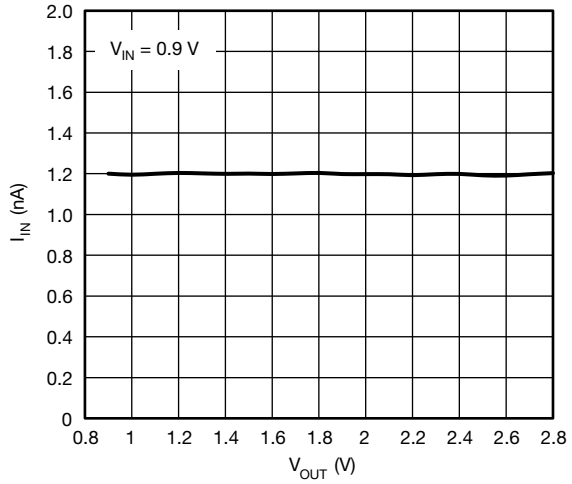

Fig. 16 - Reverse Blocking Current vs. Output Voltage

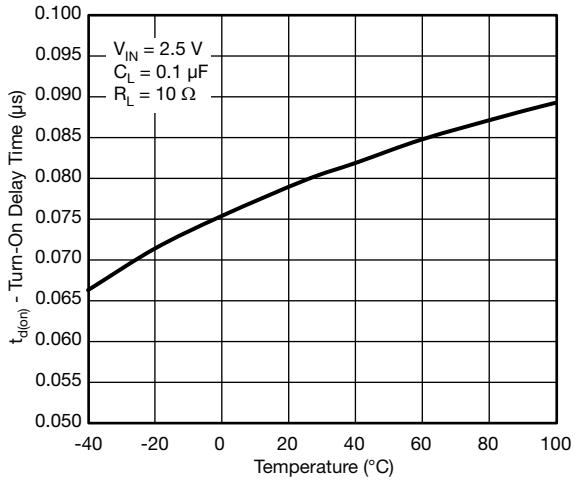

Fig. 19 - Turn-On Delay Time vs. Temperature

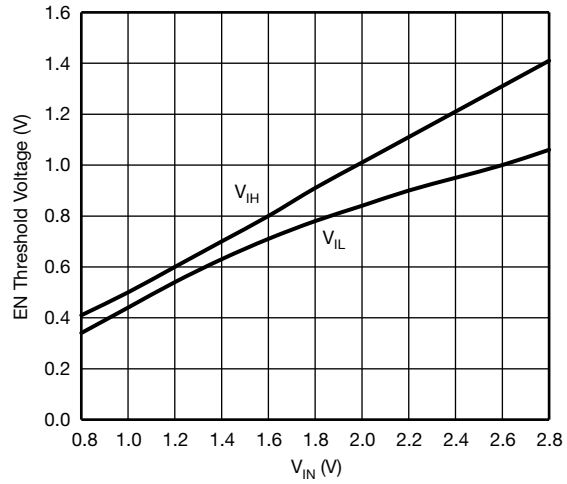

Fig. 17 - EN Threshold Voltage vs. Input Voltage

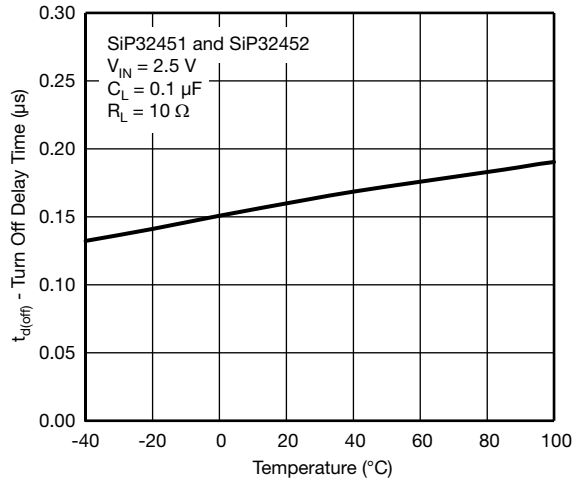

Fig. 20 - Turn-Off Delay Time vs. Temperature

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

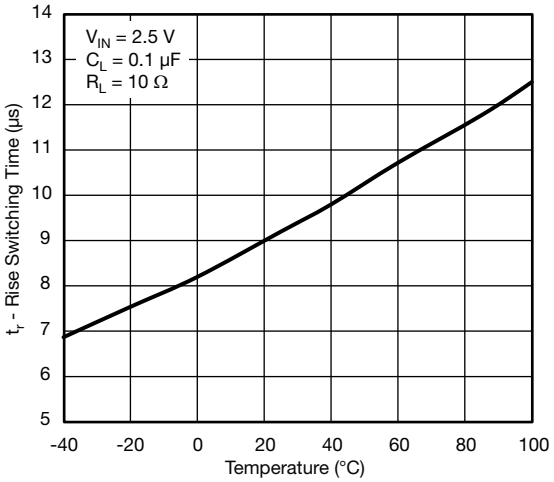

Fig. 21 - Rise Time vs. Temperature

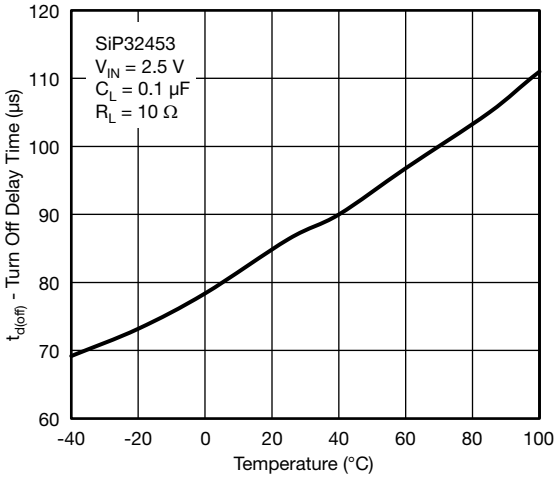

Fig. 22 - Turn-Off Delay Time vs. Temperature

TYPICAL WAVEFORMS

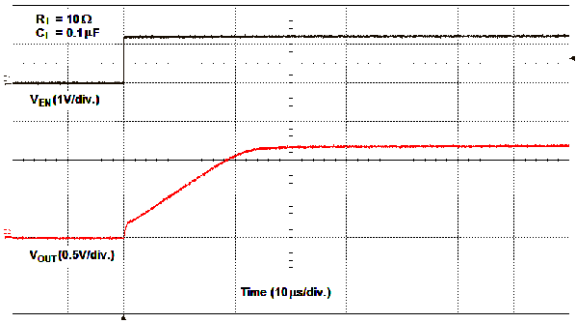

Fig. 23 - Turn-On Time (V_{IN} = 1.2 V)

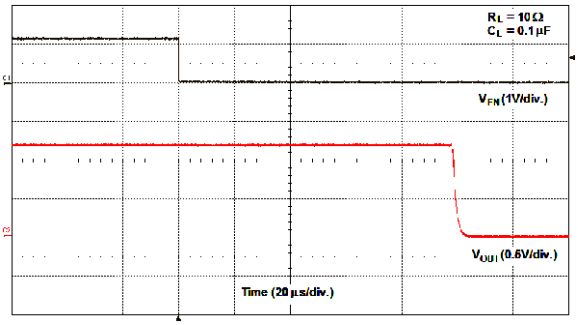

Fig. 25 - SiP32453 Turn-Off Time (V_{IN} = 1.2 V)

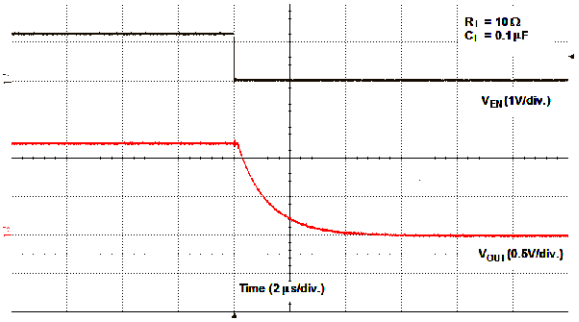

Fig. 24 - SiP32451 and SiP32452 Turn-Off Time (V_{IN} = 1.2 V)

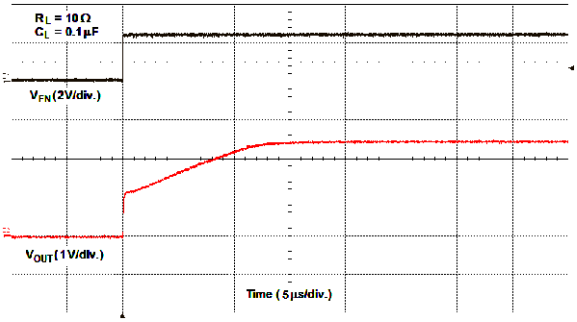

Fig. 26 - Turn-On Time (V_{IN} = 2.5 V)

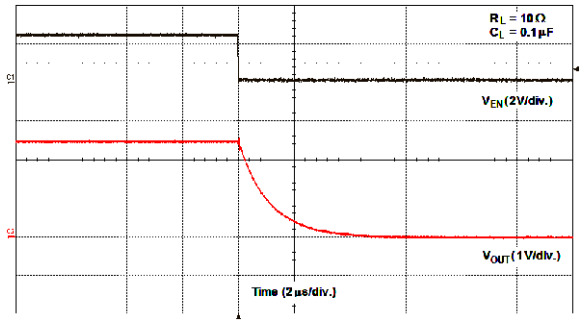

Fig. 27 - SiP32451 and SiP32452 Turn-Off Time (V_{IN} = 2.5 V)

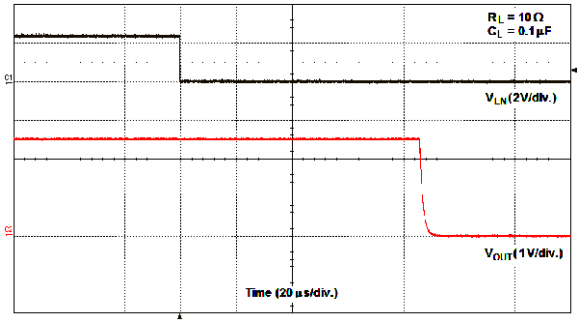

Fig. 28 - SiP32453 Turn-Off Time (V_{IN} = 2.5 V)

BLOCK DIAGRAM

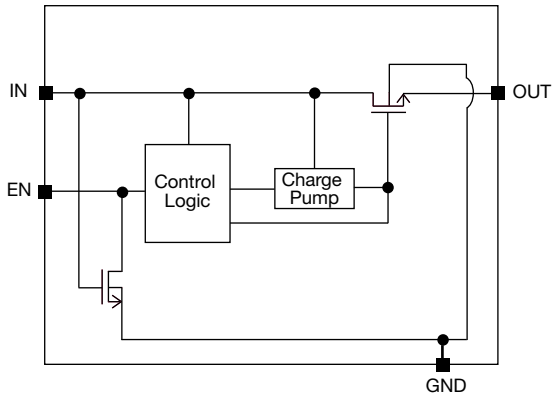

Fig. 29 - Functional Block Diagram

DETAILED DESCRIPTION

SiP32451, SiP32452, and SiP32453 are n-channel power MOSFET designed as high side load switch. Once enable the device charge pumps the gate of the power MOSFET to a constant gate to source voltage for fast turn on time. The mostly constant gate to source voltage keeps the on resistance low through out the input voltage range. When disable, the SiP32451 and SiP32452 pull the gate of the output n-channel low right away for a fast turn off delay while there is a build-in turn off delay for the SiP32453. The SiP32451 especially features a output discharge circuit to help discharge the output capacitor. The turn off delay for the SiP32453 is guaranteed to be at least 30 µs. Because the body of the output n-channel is always connected to GND, it prevents the current from going back to the input in case the output voltage is higher than the output.

APPLICATION INFORMATION

Input Capacitor

While a bypass capacitor on the input is not required, a 4.7 µF or larger capacitor for C_{IN} is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the input pin to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

Output Capacitor

A 0.1 µF capacitor across V_{OUT} and GND is recommended to insure proper slew operation. There is inrush current through the output MOSFET and the magnitude of the inrush current depends on the output capacitor, the bigger the C_{OUT} the higher the inrush current. There are no ESR or capacitor type requirement.

Enable

The EN pin is compatible with CMOS logic voltage levels. It requires at least 0.1 V or below to fully shut down the device and 1.5 V or above to fully turn on the device.

Protection Against Reverse Voltage Condition

SiP32451, SiP32452, and SiP32453 can block the output current from going to the input in case where the output voltage is higher than the input voltage when the main switch is off.

Thermal Considerations

These devices are designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 1.2 A as stated in the Absolute Maximum Ratings table. However,

another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 280 °C/W) the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature, T_J (max.) = 125 °C, the junction-to-ambient thermal resistance, θ_{J-A} = 280 °C/W, and the ambient temperature, T_A, which may be formulaically expressed as:

$$P\ (max.) = \frac{T_{J(max.)} - T_A}{\theta_{JA}} = \frac{125 - T_A}{280}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 196 mW.

So long as the load current is below the 1.2 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the $R_{DS(on)}$ at the ambient temperature.

As an example let us calculate the worst case maximum load current at T_A = 70 °C. The worst case $R_{DS(on)}$ at 25 °C is 65 mΩ. The $R_{DS(on)}$ at 70 °C can be extrapolated from this data using the following formula:

$R_{DS(on)}$ (at 70 °C) = $R_{DS(on)}$ (at 25 °C) x (1 + T_C x ΔT)

Where T_C is 3900 ppm/°C. Continuing with the calculation we have

$R_{DS(on)}$ (at 70 °C) = 65 mΩ x (1 + 0.0039 x (70 °C - 25 °C)) = 76.4 mΩ

The maximum current limit is then determined by

$$I_{LOAD(max.)} < \sqrt{\frac{P\ (max.)}{R_{DS(on)}}}$$

which in this case is 1.6 A. Under the stated input voltage condition, if the 1.6 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 1.2 A only as listed in the Absolute Maximum Ratings table.

PRODUCT SUMMARY			
Part number	SiP32451	SiP32452	SiP32453
Description	0.9 V to 2.5 V, 55 mΩ, bidirectional off isolation, fast turn on / off, output discharge	0.9 V to 2.5 V, 55 mΩ, bidirectional off isolation, fast turn on / off	0.9 V to 2.5 V, 55 mΩ, bidirectional off isolation, fast turn on and 98 µs turn off delay
Configuration	Single	Single	Single
Slew rate time (µs)	20	20	20
On delay time (µs)	0.4	0.4	0.4
Input voltage min. (V)	0.9	0.9	0.9
Input voltage max. (V)	2.5	2.5	2.5
On-resistance at input voltage min. (mΩ)	56	56	56
On-resistance at input voltage max. (mΩ)	54	54	54
Quiescent current at input voltage min. (µA)	4	4	4
Quiescent current at input voltage max. (µA)	32	32	32
Output discharge (yes / no)	Yes	No	No
Reverse blocking (yes / no)	Yes	Yes	Yes
Continuous current (A)	1.2	1.2	1.2
Package type	WCSP4	WCSP4	WCSP4
Package size (W, L, H) (mm)	0.8 x 0.8 x 0.5	0.8 x 0.8 x 0.5	0.8 x 0.8 x 0.5
Status code	2	2	2
Product type	Slew rate	Slew rate	Slew rate
Applications	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable

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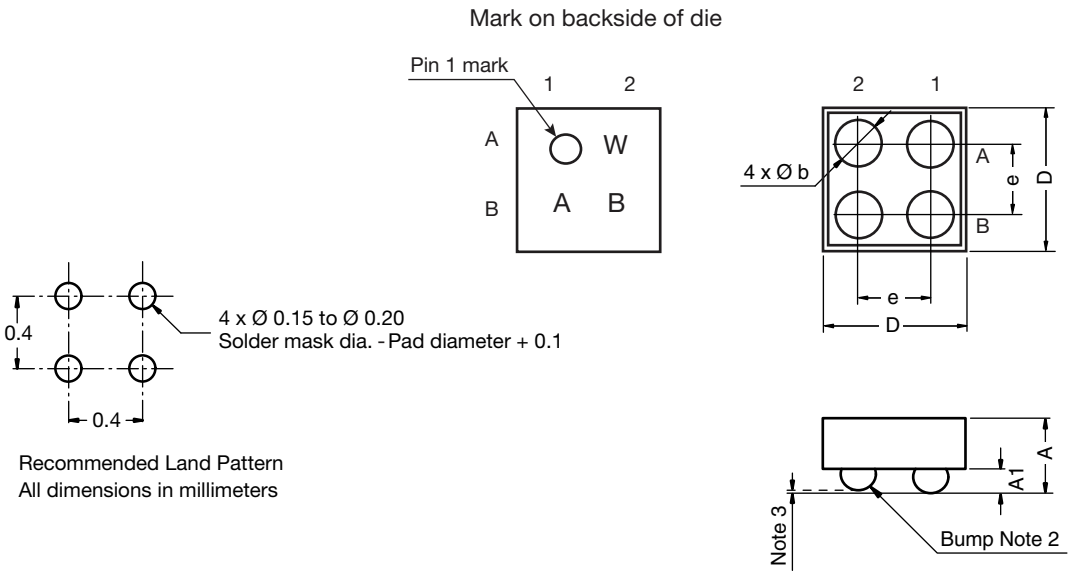
WCSP4: 4 Bumps

(2 x 2, 0.4 mm pitch, 208 µm bump height, 0.8 mm x 0.8 mm die size)



Recommended Land Pattern
All dimensions in millimeters

DWG-No: 6004

Notes

(1) Laser mark on the backside surface of die
(2) Bumps are SAC396
(3) 0.05 max. coplanarity

DIM.	MILLIMETERS [a]			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.515	0.530	0.545	0.0203	0.0209	0.0215
A1		0.208			0.0082	
b	0.250	0.260	0.270	0.0098	0.0102	0.0106
e		0.400			0.0157	
D	0.720	0.760	0.800	0.0283	0.0299	0.0315

Note

a. Use millimeters as the primary measurement

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